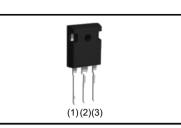


RGS60TS65HR

650V 30A Field Stop Trench IGBT

V _{CES}	650V
I _{C (100°C)}	30A
V _{CE(sat) (Typ.)}	1.65V
P _D	223W

Outline TO-247N



Inner Circuit

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) Short Circuit Withstand Time 8µs
- 3) Qualified to AEC-Q101
- 4) Pb free Lead Plating ; RoHS Compliant

Application

Heater for Automotive

		I	(2)
((1) O		
			(3)



Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGS60TS65

•Absolute Maximum Ratings (at T_c = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V _{GES}	±30	V
Collector Current	$T_{\rm C}$ = 25°C	Ι _C	56	А
Collector Current	T _C = 100°C	Ι _C	30	А
Pulsed Collector Current		I _{CP} *1	90	А
Power Dissinction	$T_{C} = 25^{\circ}C$	P _D	223	W
Power Dissipation	T _C = 100°C	P _D	111	W
Operating Junction Temperature		Tj	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

*1 Pulse width limited by T_{imax.}

•Thermal Resistance

Parameter	Symbol	Values			Unit
Parameter	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.67	°C/W

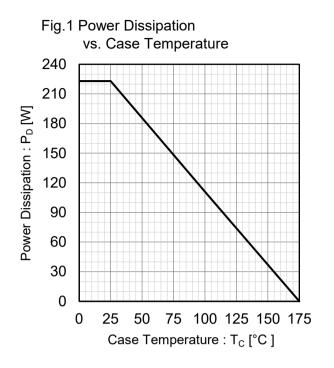
●IGBT Electrical Characteristics (at T_i = 25°C unless otherwise specified)

Parameter	Symbol	Conditions		Values	Unit		
Farameter	Symbol Conditions		Min.	Тур.	Max.	Onit	
Collector - Emitter Breakdown Voltage	BV _{CES}	I _C = 10μΑ, V _{GE} = 0V	650	-	-	V	
		V _{CE} = 650V, V _{GE} = 0V,					
Collector Cut - off Current	I _{CES}	T _j = 25℃ Tj = 175℃ ^{*2}	-	-	10	μA	
		Tj = 175°C ^{*2}	-	-	5	mA	
Gate - Emitter Leakage Current	I _{GES}	V_{GE} = ±30V, V_{CE} = 0V	-	-	±200	nA	
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	V _{CE} = 5V, I _C = 1.5mA	5.0	6.0	7.0	V	
		I _C = 30A, V _{GE} = 15V,					
Collector - Emitter Saturation Voltage	V _{CE(sat)}	T _j = 25°C	-	1.65	2.10	V	
		T _j = 175°C	-	2.15	-	V	

•IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Deremeter	Symbol	Conditions	Values			L Incit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input Capacitance	C _{ies}	V _{CE} = 30V,	-	980	-		
Output Capacitance	C _{oes}	V _{GE} = 0V,	-	80	-	pF	
Reverse transfer Capacitance	C _{res}	f = 1MHz	-	13	-		
Total Gate Charge	Qg	V _{CE} = 300V,	-	36	-		
Gate - Emitter Charge	Q_{ge}	I _C = 30A,	-	10	-	nC	
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	15	-		
Turn - on Delay Time	t _{d(on)}		-	28	-		
Rise Time	t _r	I _C = 30A, V _{CC} = 400V, V _{GE} = 15V, R _G = 10Ω,	-	12	-		
Turn - off Delay Time	t _{d(off)}	$T_i = 25^{\circ}C$	-	104	-	ns	
Fall Time	t _f	Inductive Load	-	101	-		
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	0.66	-	mJ	
Turn - off Switching Loss	E _{off}		-	0.81	-		
Turn - on Delay Time	t _{d(on)}		-	29	-		
Rise Time	t _r	I _C = 30A, V _{CC} = 400V, V _{GE} = 15V, R _G = 10Ω,	-	17	-	ns	
Turn - off Delay Time	t _{d(off)}	$T_i = 175^{\circ}C$	-	131	-		
Fall Time	t _f	Inductive Load	-	159	-		
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	0.88	-	ml	
Turn - off Switching Loss	E _{off}	,	-	1.13	-	mJ	
		I _C = 90A, V _{CC} = 520V,					
Reverse Bias Safe Operating Area	RBSOA	V _P = 650V, V _{GE} = 15V,	FULL SQUARE			-	
ouro oporating / tou		R _G = 50Ω, T _j = 175°C					
Short Circuit Withstand Time	t _{sc}	V _{CC} ≤ 360V, V _{GE} = 15V, T _j = 25°C	8	-	-	μs	
Short Circuit Withstand Time	t _{sc} *2	V _{CC} ≤ 360V, V _{GE} = 15V, T _j = 150°C	6	-	-	μs	

*2 Design assurance without measurement



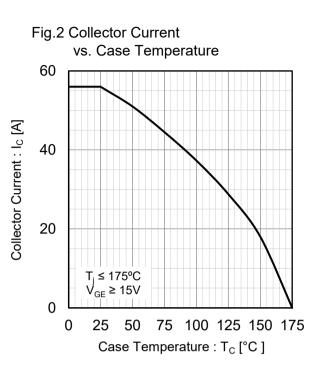
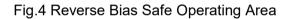
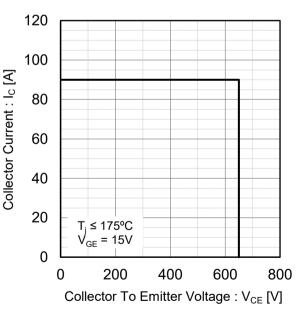


Fig.3 Forward Bias Safe Operating Area 1000 10µs 100 Collector Current : I_c [A] 10 100µs 1 0.1 T_C = 25°C Single Pulse 0.01 10 100 1000 1 Collector To Emitter Voltage : V_{CE} [V]





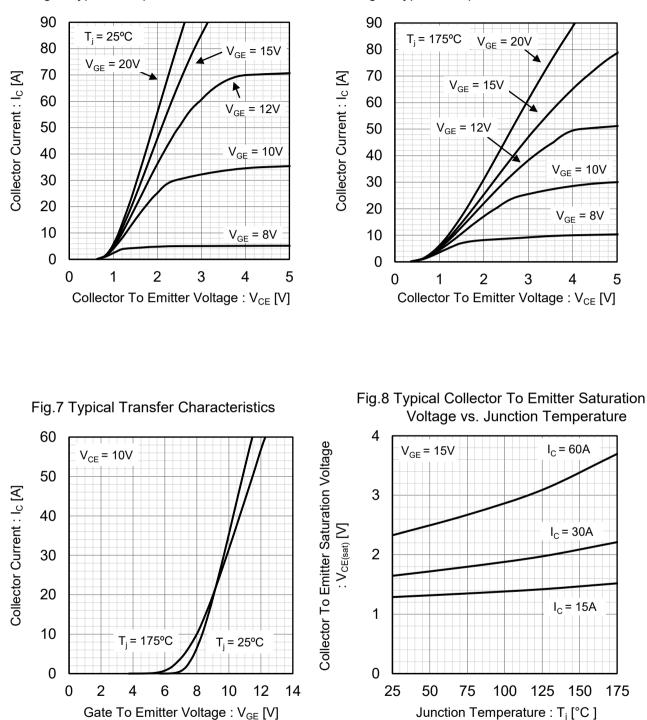
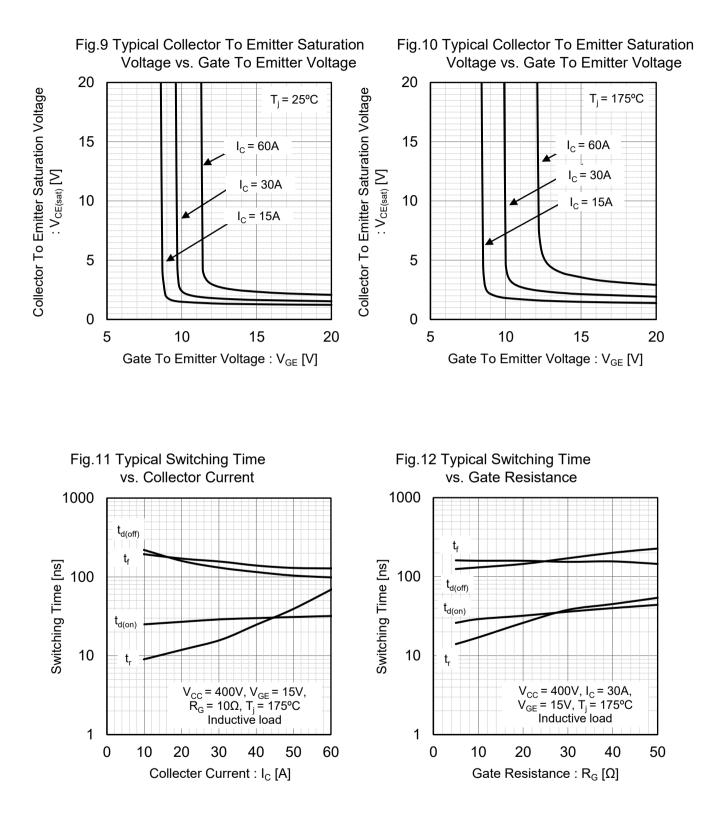
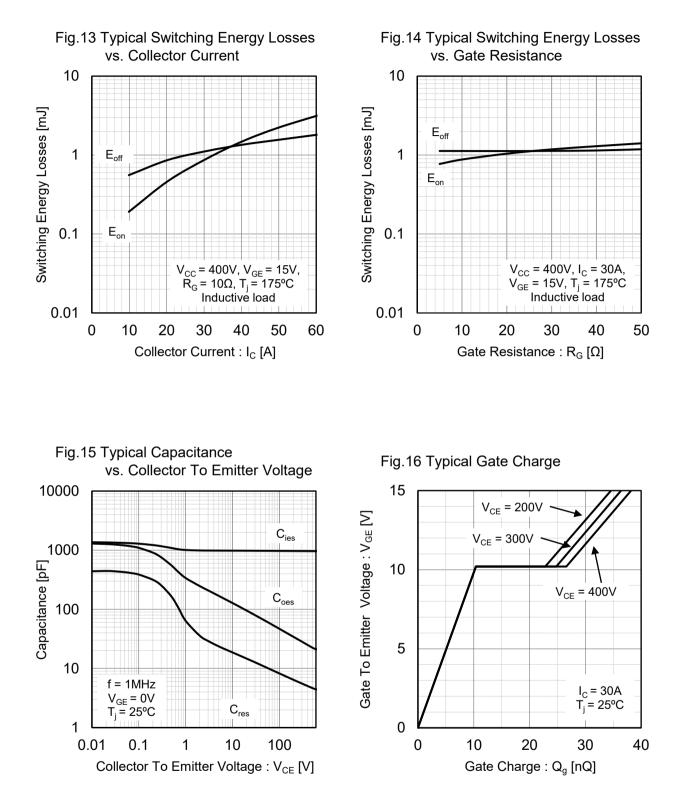


Fig.5 Typical Output Characteristics

Fig.6 Typical Output Characteristics



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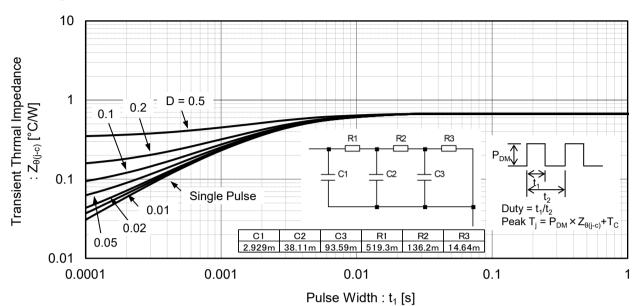


Fig.17 IGBT Transient Thermal Impedance

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Inductive Load Switching Circuit and Waveform

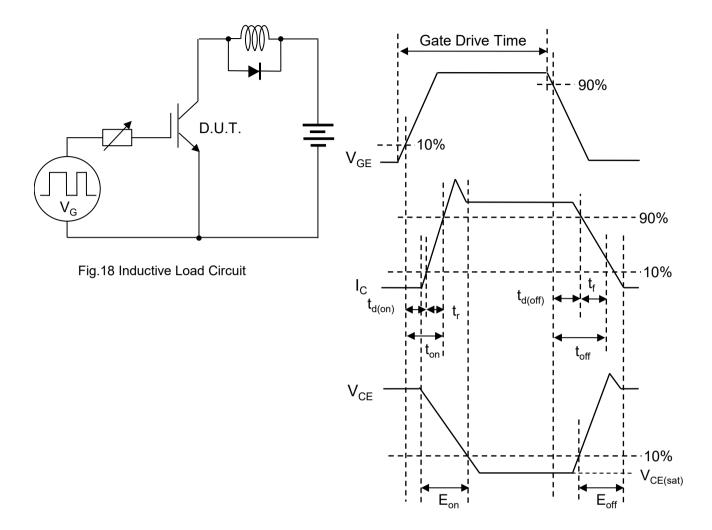


Fig.19 Inductive Load Waveform

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